# VS-VSKCS201/045

**Vishay Semiconductors** 

COMPLIANT





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PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	200 A			
V <sub>R</sub>	45 V			
Package	AAP Gen 7 (TO-240AA)			
Circuit configuration	Two diodes common cathode			

## **MECHANICAL DESCRIPTION**

The AAP Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

## FEATURES

- 175 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation
- Low thermal resistance
- UL approved file E78996
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- Easy mounting on heatsink

### **ELECTRICAL DESCRIPTION / APPLICATIONS**

The VS-VSKCS201.. Schottky rectifier common cathode has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>F(AV)</sub>	Rectangular waveform	200	А		
V <sub>RRM</sub>		45	V		
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	8600	А		
V <sub>F</sub>	100 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.69	V		
TJ	Range	-55 to +175	C°		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-VSKCS201/045	UNITS		
Maximum DC reverse voltage	V <sub>R</sub>	45	V		
Maximum working peak reverse voltage	V <sub>RWM</sub>	40	V		

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# VS-VSKCS201/045

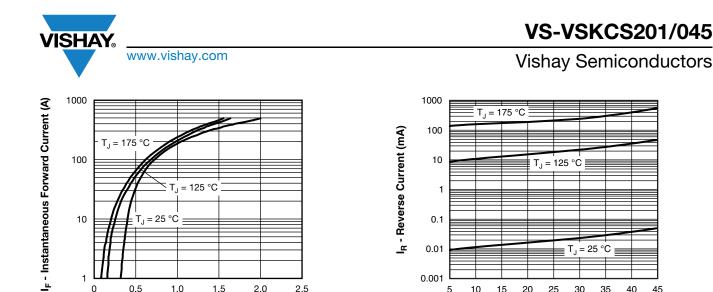
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ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum averageper moduleforward currentper leg			50 % duty cycle at $T_{C}$ = 123 °C, rectangular waveform		200	
		I <sub>F(AV)</sub>			100	
Maximum peak one cycle		1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	8600	А
non-repetitive surge current		I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	rated $V_{RRM}$ applied	1850	
Non-repetitive avalanche energy		E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 24 A, L = 1 mH		270	mJ
Repetitive avalanche current		I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		20	А

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
	V <sub>FM</sub>	100 A	T <sub>J</sub> = 25 °C	0.72	V
Maximum forward voltage drop		200 A		1.04	
Maximum forward voltage drop		100 A	- T <sub>J</sub> = 125 °C	0.69	
		200 A		0.98	
	I <sub>RM</sub>	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>R</sub>	10	mA
Maximum reverse leakage current		T <sub>J</sub> = 125 °C		90	
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		5200	pF
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		7.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs
Maximum RMS insulation voltage	V <sub>INS</sub>	50 Hz		3000 (1 min) 3600 (1 s)	V

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	)	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C	
Maximum thermal resistance, junction to case per leg RthJC DC oper   Typical thermal resistance, case to heatsink per module RthCs		R <sub>thJC</sub>	DC operation	0.52	°C/W	
			0.1	C/W		
A				75	g	
Approximate weight				2.7	oz.	
Mounting torgue ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for	4	Nm	
	busbar		the spread of the compound.	3		
Case style			JEDEC	TO-240AA co	mpatible	

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V<sub>FM</sub> - Forward Voltage Drop (V)

1.5

2.0

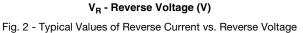
2.5

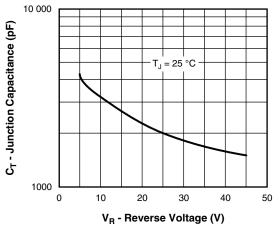
Fig. 1 - Maximum Forward Voltage Drop Characteristics

1.0

1 0

0.5





0.001

5 10 15 20 25 30 35 40 45

Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

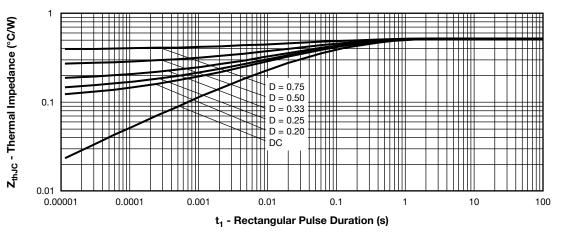
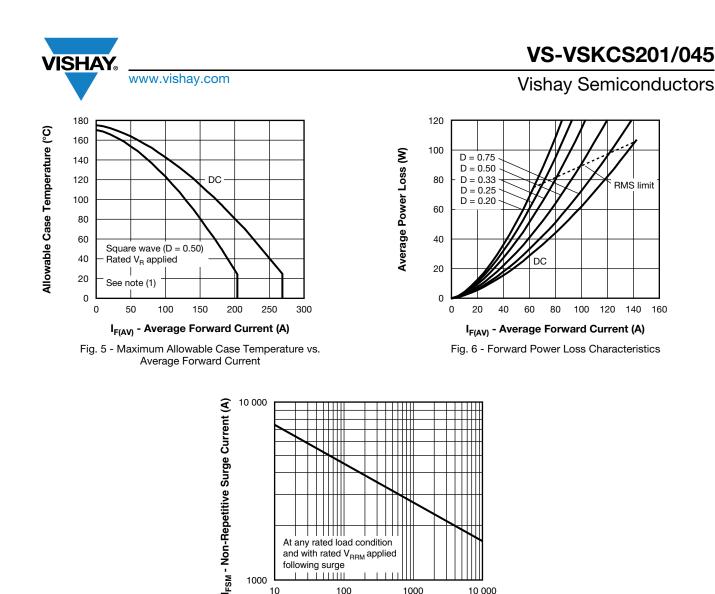


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

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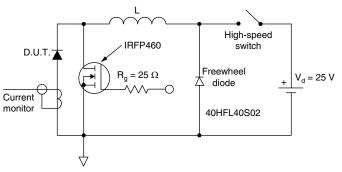


At any rated load condition and with rated V<sub>RRM</sub> applied

100

following surge 

1000 10



t<sub>n</sub> - Square Wave Pulse Duration (µs) Fig. 7 - Maximum Non-Repetitive Surge Current

1000

10 000



#### Note

- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ;
  - $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$  (see fig. 6);
  - $Pd_{REV}$  = inverse power loss =  $V_{R1} \times I_R (1 D)$ ;  $I_R$  at  $V_{R1}$  = 80 % rated  $V_R$

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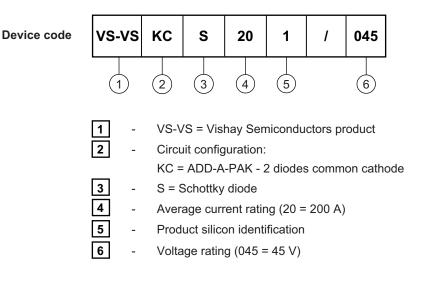
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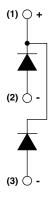
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## **ORDERING INFORMATION TABLE**



### **CIRCUIT CONFIGURATION**



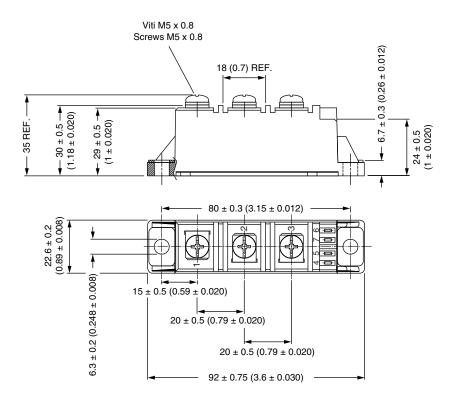
LINKS TO RELATED D	OCUMENTS
Dimensions	www.vishay.com/doc?95369

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# **ADD-A-PAK Generation VII - Diode**

## **DIMENSIONS** in millimeters (inches)





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